PSG COLLEGE OF ARTS & SCIENCE

(AUTONOMOUS)

BSc DEGREE EXAMINATION DECEMBER 2019

(First Semester)

Branch - **ELECTRONICS**

SEMICONDUCTOR DEVICES

Time:	Three Hours		Maximum: 75 Marks
	Answer A	N-A go Marks) ALL questions carry EQUAL marks	(10x1 = 10)
1	materials have the resis insulator. (i) conductor (iii) semiconductor	tance levels between a (ii) insulator (iv) all of the above	a conductor and an.
2	The transfer of electrons from N produces a voltage . (i) barrier (iii) knee	` '	P side in a junction
3		rect conductor when v	
4	Practical diode draws very low (i) current (iii) energy	when reverse (ii) voltage (iv) power	e biased.
	is a semiconductor (i) amplifier (iii) inductor	device that can both c 00 transistor (iv) capacitor	conduct and insulate.
	FET is terminal semico (i) one (iii) three	onductor device, (ii) two (iv) four	
	effect is the transfer o (i) Photoluminescence (iii) Photoconductive	f energy from the light (ii) Photo emissive (iv) Photoelectric	t to an electron.
	is made of two pieces o (i) OLD (iii) LED	f polarized glass. (ii) LDR (iv) LCD	
	The varactor diode always works (i) forward (iii) positive	in bias. (ii) reverse (iv) neutral	
10 The	e UJT can be used as (i) phase control (iii) timing circuit	(ii) triggering device (iv) all of the above	

C'ont...

SECTION - B (25 Marks!

Answer **ALL** questions

ALL questions cany **EQUAL** Marks (5x5-25)

11 a Prepare an introduction for semiconductors.

OR

- b Outline the effect of temperature oh semiconductor.
- 12 a Bring out the basics of PN junction diode.

OR

- b Show through circuit diagram that how zener diode acts as voltage regulator.
- 13 a Narrate important points on transistor is used as a switch.

OR

- b Sketch a neat diagram that how FET acts as a voltage variable resistor and explain
- 14 a State photo emissive theory.

OR

- b What is LDR and where it is used?
- 15 a Outline the basic theory of varactar diode.

OR

b Compare DIAC and TRIAC and tabulate the findings.

SECTION -C (40 Marks)

Answer **ALL** questions

ALL questions carry EQUAL Marks (5x8 = 40)

16 a Discuss in detail about the energy band theory of semiconductors.

OF

- b What is intrinsic semiconductor and explain its characteristics?
- 17 a Differentiate between static and dynamic resistance.

OR

- b Explain in detail about the reverse recovery time.
- 18 a Classify the types of transistors and explain about the CB configuration in detail.

OR

- b Elucidate about the depletion type MOSFET and its working.
- 19 a Enumerate the Characteristics of LED.

OR

- b Highlight the basics of opto couplers.
- 20 a Explain the theory of schottky barrier diode.

OR

b What is MOV? Explain its construction and working.

z-z-z END